2SA1617

Silicon PNP Epitaxial

HITACHI

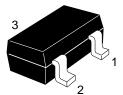
ADE-208-1022A (Z) 2nd. Edition Mar. 2001

Application

High voltage amplifier

Outline

MPAK



- 1. Emitter
- 2. Base
- 3. Collector



2SA1617

Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	– 55	V
Collector to emitter voltage	V _{CEO}	– 50	V
Emitter to base voltage	V _{EBO}	– 5	V
Collector current	I _c	-100	mA
Collector power dissipation	P _c	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

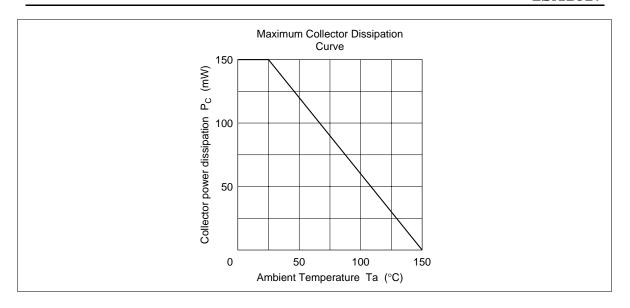
Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	- 55	_	_	V	$I_{c} = -10 \ \mu\text{A}, \ I_{e} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	– 50	_	_	V	$I_C = -1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	- 5	_	_	V	$I_E = -10 \ \mu A, \ I_C = 0$
Collector cutoff current	I _{CBO}	_	_	-0.5	μΑ	$V_{CB} = -30 \text{ V}, I_{E} = 0$
Emitter cutoff current	I_{EBO}	_	_	-0.5	μΑ	$V_{EB} = -2 \text{ V}, I_{C} = 0$
DC current transfer ratio	h _{FE} *1	100	_	320		$V_{CE} = -12 \text{ V}, I_{C} = -2 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	-0.2	V	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = -1 \text{ mA}$
Base to emitter voltage	V _{BE}	_	_	-0.8	V	$V_{CE} = -12 \text{ V}, I_{C} = -2 \text{ mA}$

Note: 1. The 2SA1617 is grouped by h_{FE} as follows.

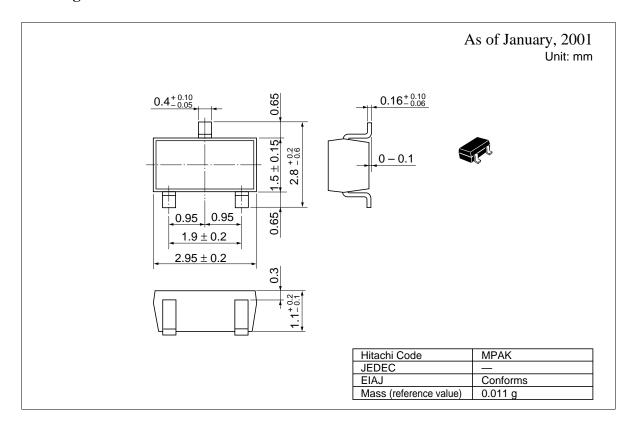
Grade	В	С
Mark	VIB	VIC
h _{FE}	100 to 200	160 to 320

See charcteristic curves of 2SA1052



2SA1617

Package Dimensions



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